NSN 5961-01-214-7045

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View Online at https://aerobasegroup.com/nsn/5961-01-214-7045 **Inclosure Material:** Plastic **Overall Length:** 11.5 millimeters **Overall Height:** 3.1 millimeters **Overall Width:** 8.5 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-126 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 180.0 collector to base voltage/static/emitter open and 160.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector **Transfer Ratio:** 60.0 static forward current transfer ratio, common-emitter and 320.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No Fiig:

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